

Load Switch ICs for Portable Equipment

BD2202G-LB BD2206G-LB

General Description

This product guarantees long time support in Industrial market. The High-side switch, which has over-current protection function, is used for the power supply line of a memory card slot. In the switch part, an N-channel MOSFET with low ON resistance has been 1 circuit integrated. The switch goes OFF when the over-current condition lasts longer than the over-current shutdown time. The OFF switch is set to latch off mode. The operating voltage range is 2.7V to 3.6V and the current limit value is set on 400mA, 1A. Moreover, functions of soft start, under voltage lockout, and over temperature protection are integrated.

Features

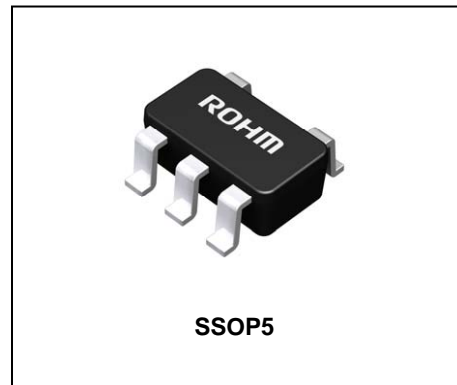
- Long time support a product for Industrial applications.
- Single low on-resistance (Typ. = 150mΩ) Nch MOS FET
- Continuous load current
 - 0.2A: (BD2202G)
 - 0.5A: (BD2206G)
- Control input logic: Active-High
- Soft start function
- Over current protection circuit
- Over temperature protection circuit
- Under voltage lockout

Key Specifications

- Input voltage range: 2.7V to 3.6V
- ON resistance : 150mΩ(Typ.)
- Over current threshold:
 - BD2202G 0.25A min., 1.0A max.
 - BD2206G 0.8A min., 1.6A max.
- Standby current: 0.01μA (Typ.)
- Operating temperature range: -25°C to +85°C

Package

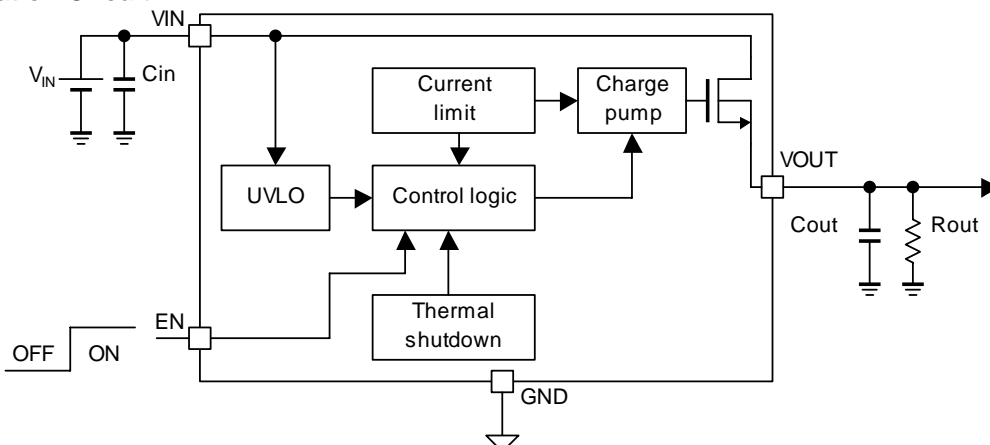
SSOP5 W(Typ.) D(Typ.) H (Max.)
2.90mm x 2.80mm x 1.25mm



Applications

Industrial Equipment, Memory card slots of STB, Digital still camera, Cell Phones, Notebook PC.

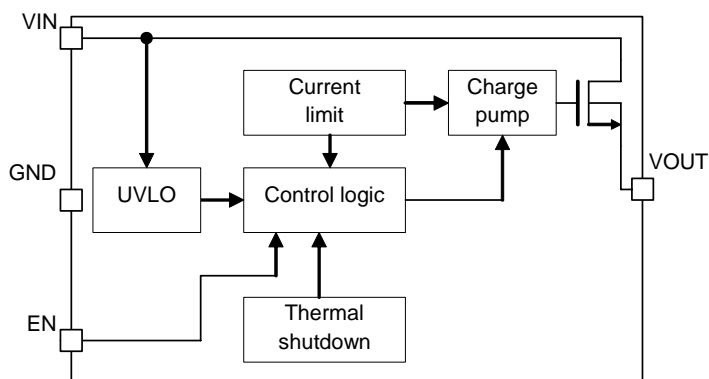
Typical Application Circuit



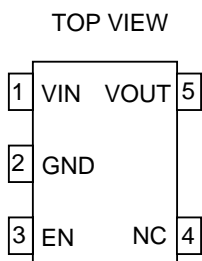
Lineup

Over current threshold			Control input logic	Package		Orderable Part Number
Min.	Typ.	Max.				
0.25A	-	1.0A	High	SSOP5	Reel of 3000	BD2202G-LBTR
0.8A	-	1.6A	High	SSOP5	Reel of 3000	BD2206G-LBTR

Block Diagram



Pin Configuration



Pin Description

Pin Number	Pin Name	I / O	Pin function
1	VIN	I	Power supply input terminal. Input terminal to the power switch and supply of the internal circuit.
2	GND	I	Ground.
3	EN	I	Power Switch enable input. Active-High Switch on input. Logic high turns the switch on.
4	N.C	-	No connection.
5	VOUT	O	Power switch output.

Absolute Maximum Ratings

Parameter	Symbol	Limits	Unit
Supply voltage	V _{IN}	-0.3 to 6.0	V
EN voltage	V _{EN}	-0.3 to 6.0	V
OUT voltage	V _{OUT}	-0.3 to V _{IN} + 0.3	V
Storage temperature	T _{STG}	-55 to 150	°C
Power dissipation	PD	675 ^{*1}	mW

*1 Mounted on 70mm * 70mm * 1.6mm grass-epoxy PCB. Derating: 5.4mW/°C for operating above Ta=25°C

Recommended Operating Range

◎BD2202G

Parameter	Symbol	Limits	Unit
Operating voltage range	V _{IN}	2.7 to 3.6	V
Operating temperature range	T _{OPR}	-25 to 85	°C
Operating load current	I _{LO}	0 to 200	mA

◎BD2206G

Parameter	Symbol	Limits	Unit
Operating voltage range	V _{IN}	2.7 to 3.6	V
Operating temperature range	T _{OPR}	-25 to 85	°C
Operating load current	I _{LO}	0 to 500	mA

Electrical Characteristics

◎BD2202G (Unless otherwise specified, V_{IN} = 3.3V, Ta = 25°C)

DC characteristics

Parameter	Symbol	Limits			Unit	Condition
		Min.	Typ.	Max.		
Operating current	I _{DD}	-	70	90	μA	V _{EN} = 3.3V, V _{OUT} = OPEN
Standby current	I _{STB}	-	0.01	1	μA	V _{EN} = 0V, V _{OUT} = OPEN
EN input voltage	V _{EN}	2.0	-	-	V	High level input
		-	-	0.8	V	Low level input
EN input current	I _{EN}	-1.0	0.01	1.0	μA	V _{EN} = 0V or V _{EN} = 3.3V
ON resistance	R _{ON}	-	150	200	mΩ	I _{OUT} = 50mA
Over-current Threshold	I _{TH}	0.25	-	1.0	A	
Short-circuit output current	I _{SC}	200	-	600	mA	V _{OUT} = 0V
Output leak current	I _{LEAK}	-	0.01	10	μA	V _{EN} = 0V, V _{OUT} = 0V
UVLO threshold	V _{TUVH}	2.1	2.3	2.5	V	V _{IN} increasing
	V _{TUVL}	2.0	2.2	2.4	V	V _{IN} decreasing

AC characteristics

Parameter	Symbol	Limits			Unit	Condition
		Min.	Typ.	Max.		
Output rise time	T _{ON1}	0.25	1.2	6	ms	R _{OUT} =500Ω, C _{OUT} =0.1μF
Output turn on time	T _{ON2}	0.4	2	10	ms	R _{OUT} =500Ω, C _{OUT} =0.1μF
Output fall time	T _{OFF1}	50	100	200	μs	R _{OUT} =500Ω, C _{OUT} =0.1μF
Output turn off time	T _{OFF2}	50	100	200	μs	R _{OUT} =500Ω, C _{OUT} =0.1μF
Over current shutdown time 1	T _{BLANK1}	5	10	15	ms	At continuous over current
Over current shutdown time 2	T _{BLANK2}	3	-	15	ms	At discontinuous over current

Electrical Characteristics - continued©BD2206G (Unless otherwise specified, $V_{IN} = 3.3V$, $T_a = 25^\circ C$)

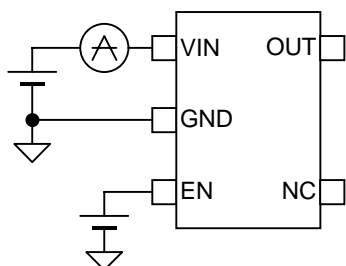
DC characteristics

Parameter	Symbol	Limits			Unit	Condition
		Min.	Typ.	Max.		
Operating current	I_{DD}	-	70	90	μA	$V_{EN} = 3.3V$, $V_{OUT} = OPEN$
Standby current	I_{STB}	-	0.01	1	μA	$V_{EN} = 0V$, $V_{OUT} = OPEN$
EN input voltage	V_{EN}	2.0	-	-	V	High level input
		-	-	0.8	V	Low level input
EN input current	I_{EN}	-1.0	0.01	1.0	μA	$V_{EN} = 0V$ or $V_{EN} = 3.3V$
ON resistance	R_{ON}	-	150	200	$m\Omega$	$I_{OUT} = 50mA$
Over-current Threshold	I_{TH}	0.8	-	1.6	A	
Short-circuit output current	I_{SC}	750	-	1350	mA	$V_{OUT} = 0V$
Output leak current	I_{LEAK}	-	0.01	10	μA	$V_{EN} = 0V$, $V_{OUT} = 0V$
UVLO threshold	V_{TUVH}	2.1	2.3	2.5	V	V_{IN} increasing
	V_{TUVL}	2.0	2.2	2.4	V	V_{IN} decreasing

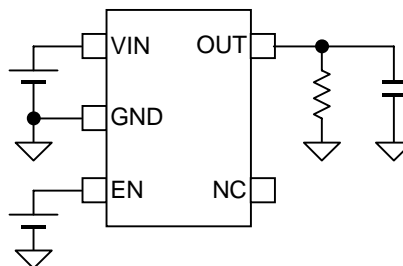
AC characteristics

Parameter	Symbol	Limits			Unit	Condition
		Min.	Typ.	Max.		
Output rise time	T_{ON1}	0.25	1.2	6	ms	$R_{OUT}=500\Omega$, $C_{OUT}=0.1\mu F$
Output turn on time	T_{ON2}	0.4	2	10	ms	$R_{OUT}=500\Omega$, $C_{OUT}=0.1\mu F$
Output fall time	T_{OFF1}	50	100	200	μs	$R_{OUT}=500\Omega$, $C_{OUT}=0.1\mu F$
Output turn off time	T_{OFF2}	50	100	200	μs	$R_{OUT}=500\Omega$, $C_{OUT}=0.1\mu F$
Over current shutdown time 1	T_{BLANK1}	5	10	15	ms	At continuous over current
Over current shutdown time 2	T_{BLANK2}	3	-	15	ms	At discontinuous over current

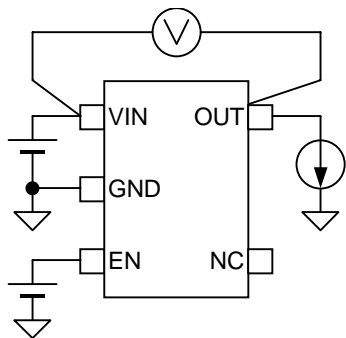
Measurement Circuits



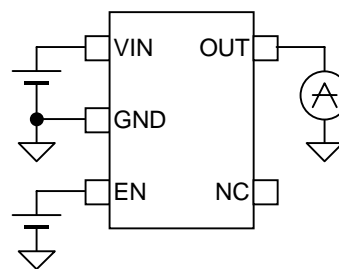
A. Operating current



B. EN input voltage, Output rise / fall time



C.ON resistance



D. Over current protection characteristics

Figure 1. Measurement circuits

Timing Diagrams

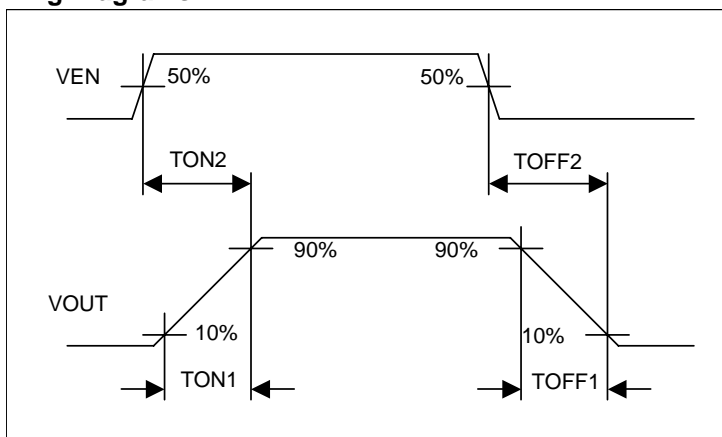


Figure 2. Switch Turn on / off time

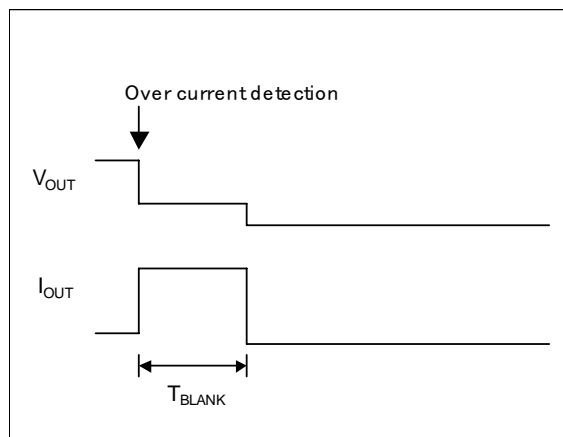


Figure 3. Over current limits characteristics

Typical Performance Curves

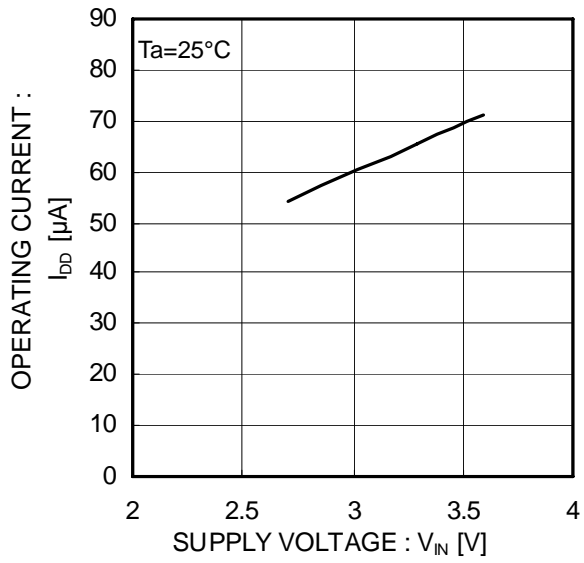


Figure 4. Operating current
EN Enable

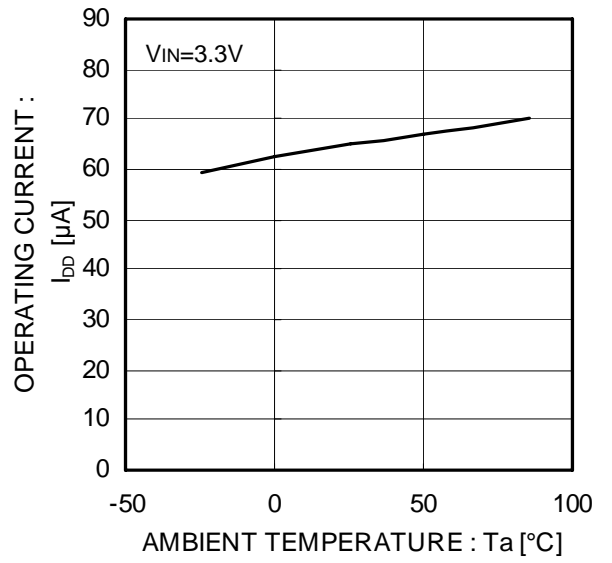


Figure 5. Operating current
EN Enable

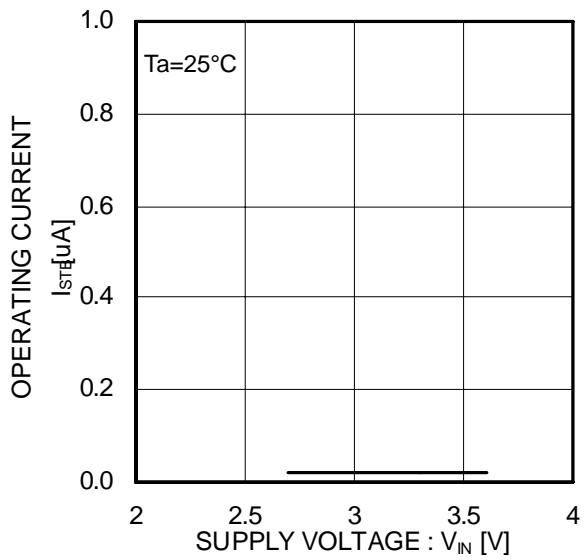


Figure 6. Operating current
EN Disable

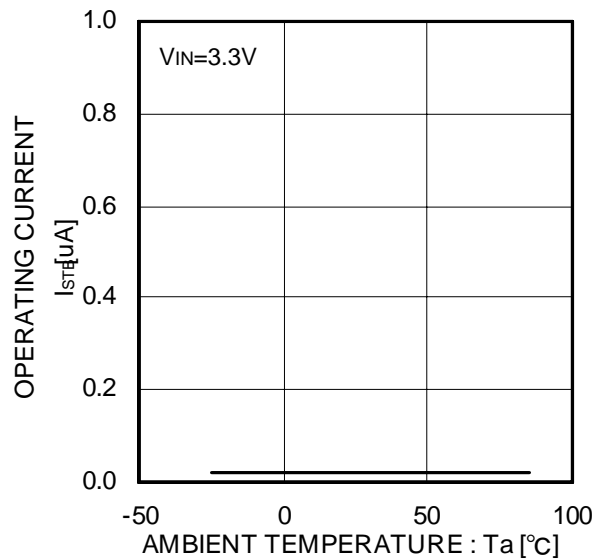


Figure 7. Operating current
EN Disable

Typical Performance Curves - continued

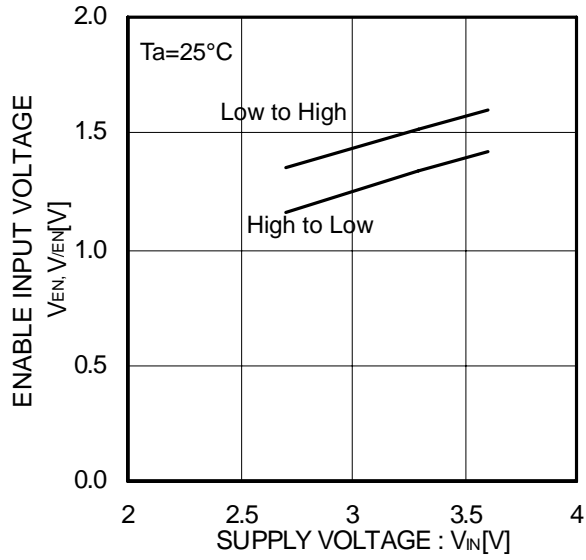


Figure 8. EN input voltage

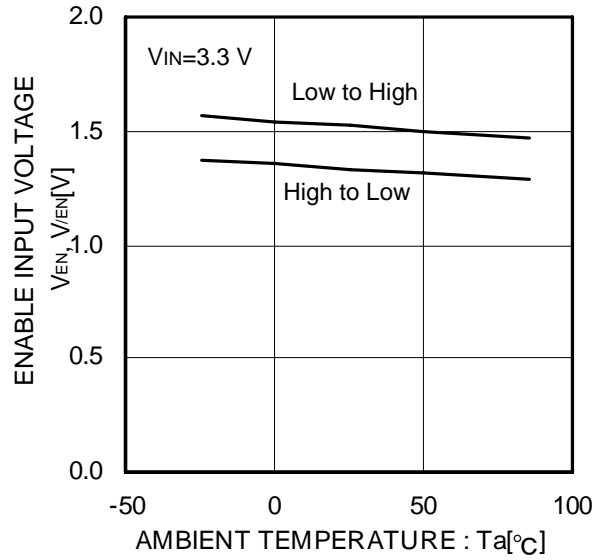


Figure 9. EN input voltage

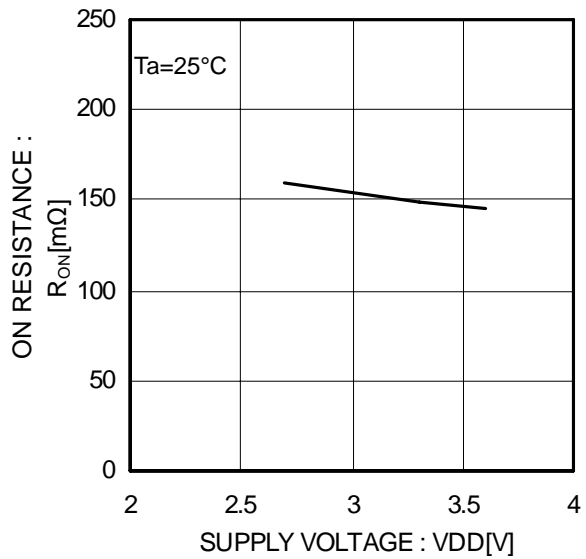


Figure 10. ON resistance

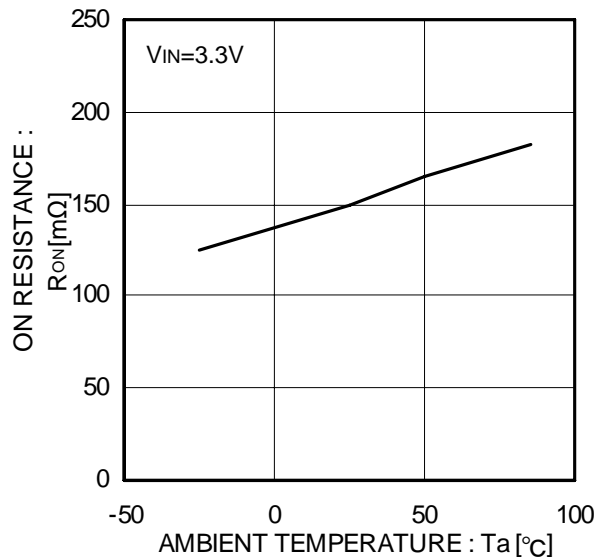


Figure 11. ON resistance

Typical Performance Curves - continued

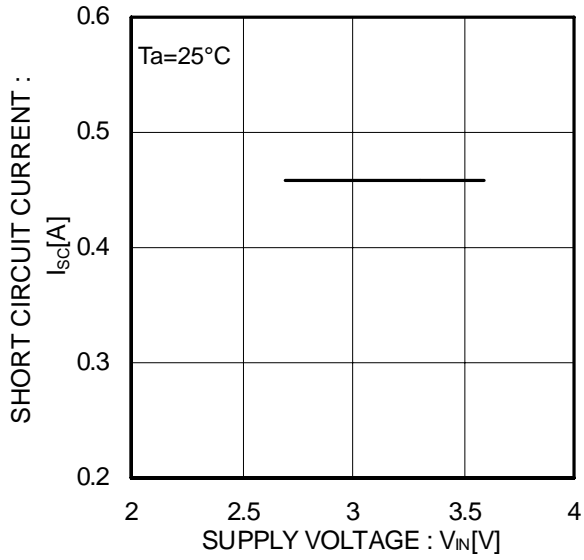


Figure 12. Short circuit output current (BD2202G)

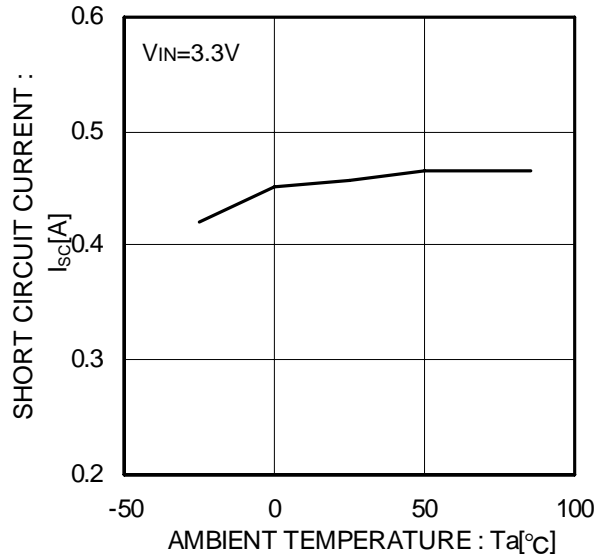


Figure 13. Short circuit output current (BD2202G)

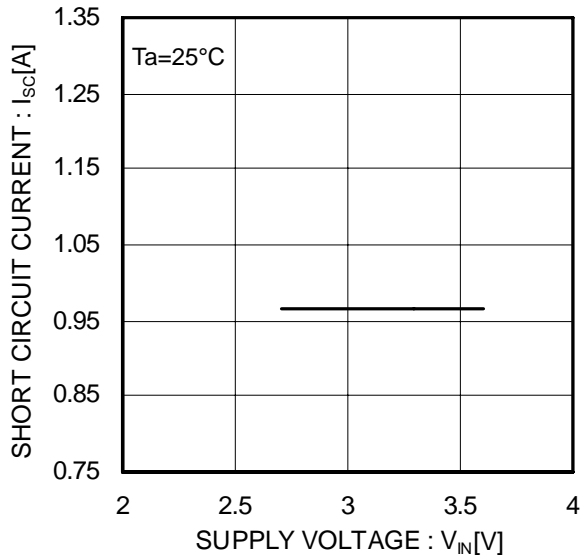


Figure 14. Short circuit output current (BD2206G)

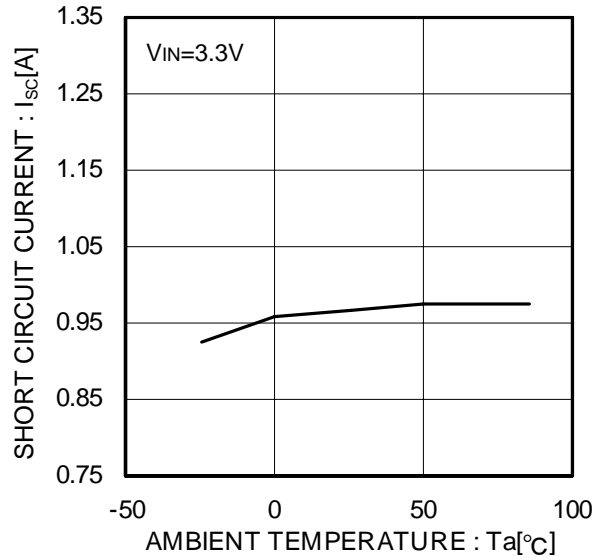


Figure 15. Short circuit output current (BD2206G)

Typical Performance Curves - continued

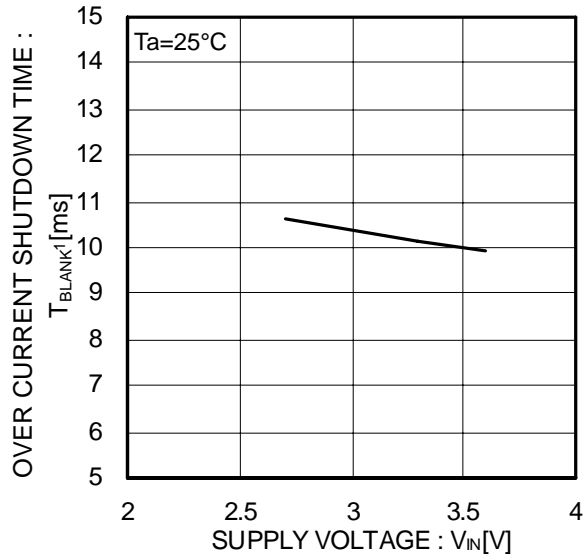


Figure 16. Over current shutdown time

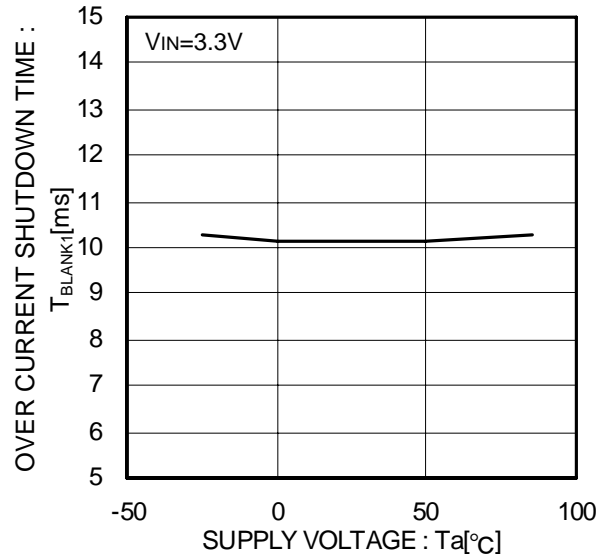


Figure 17. Over current shutdown time

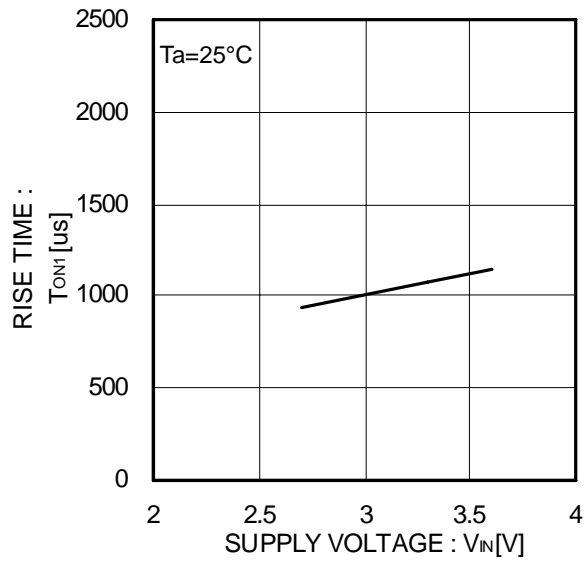


Figure 18. Output rise time

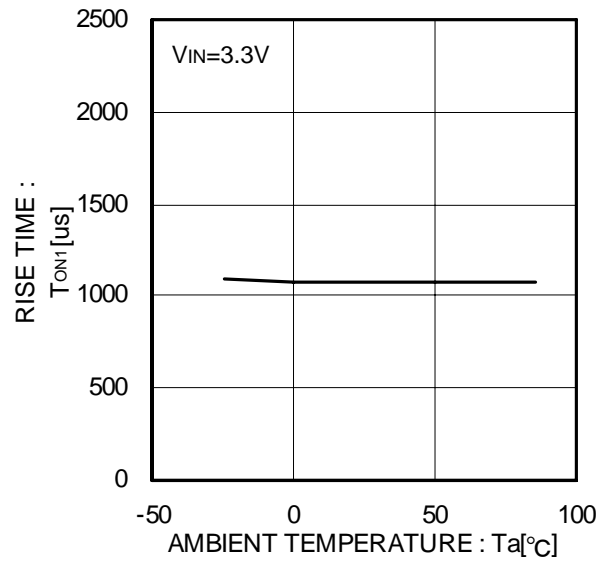


Figure 19. Output rise time

Typical Performance Curves - continued

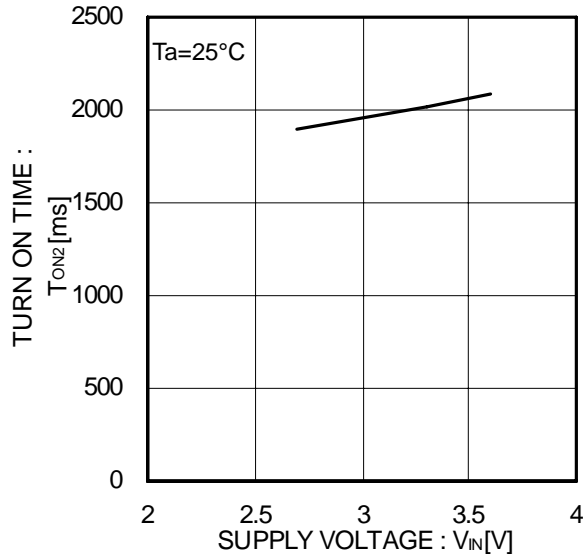


Figure 20. Output turn on time

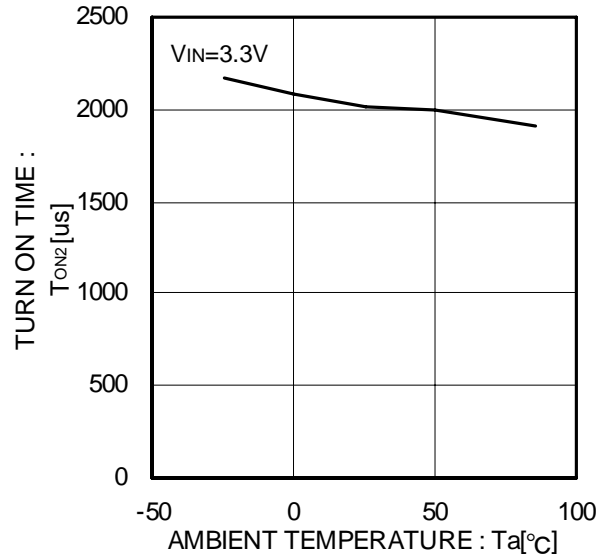


Figure 21. Output turn on time

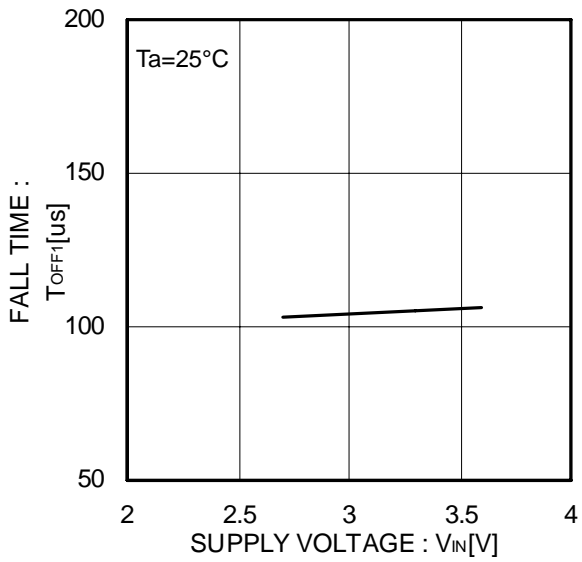


Figure 22. Output fall time

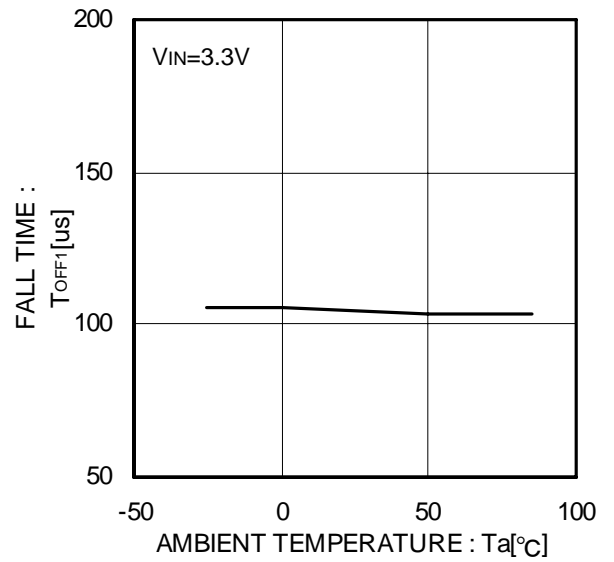


Figure 23. Output fall time

Typical Performance Curves - continued

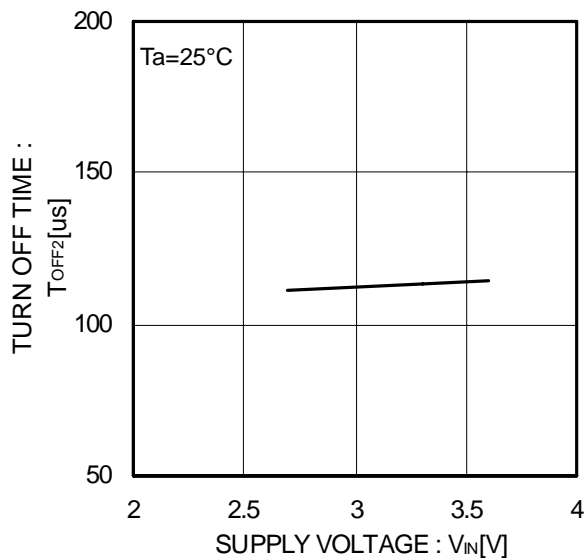


Figure 24. Output turn off time

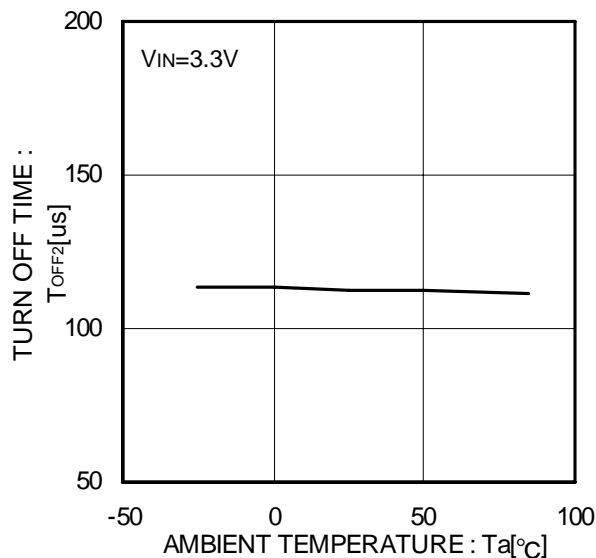


Figure 25. Output turn off time

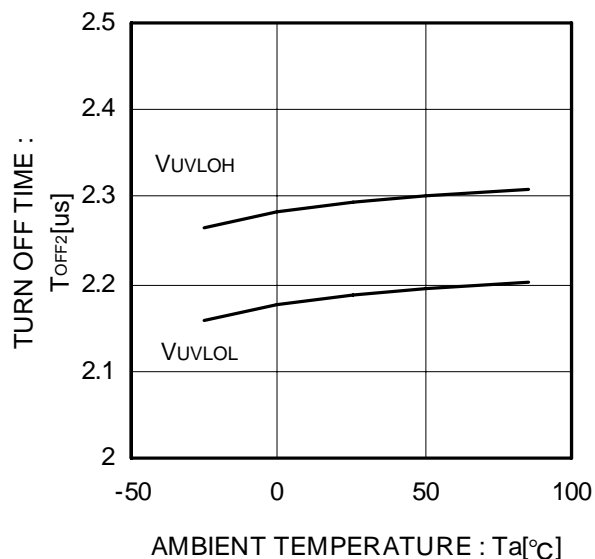


Figure 26. UVLO threshold voltage

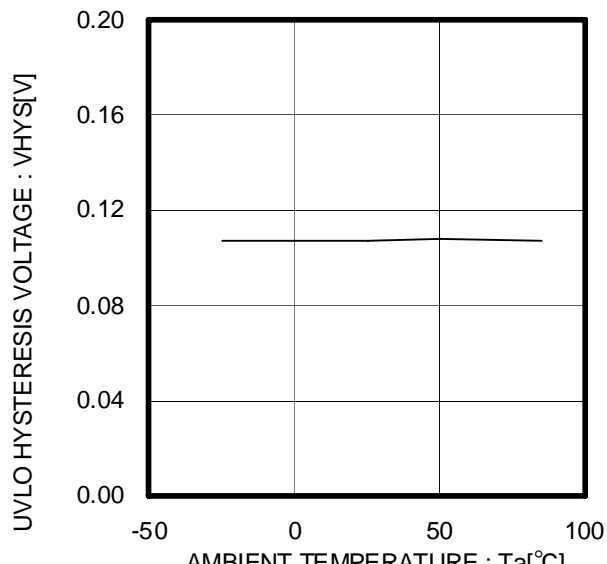


Figure 27. UVLO hysteresis voltage

Typical Wave Forms

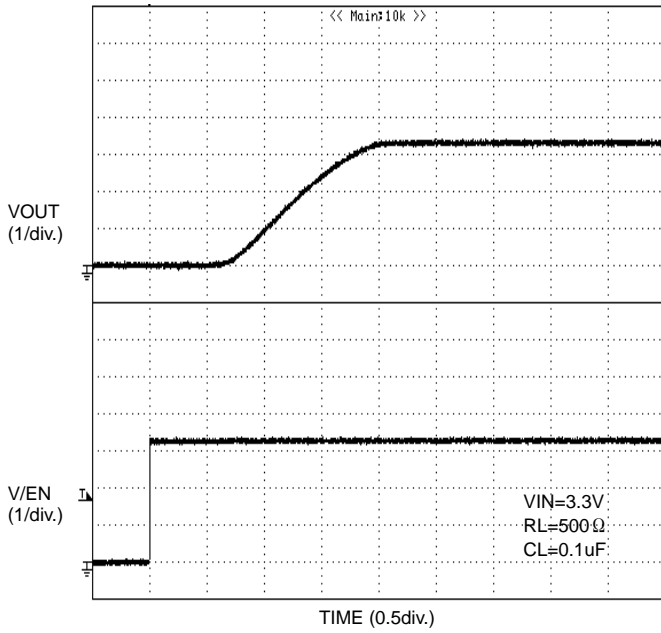


Figure 28. Output turn on response

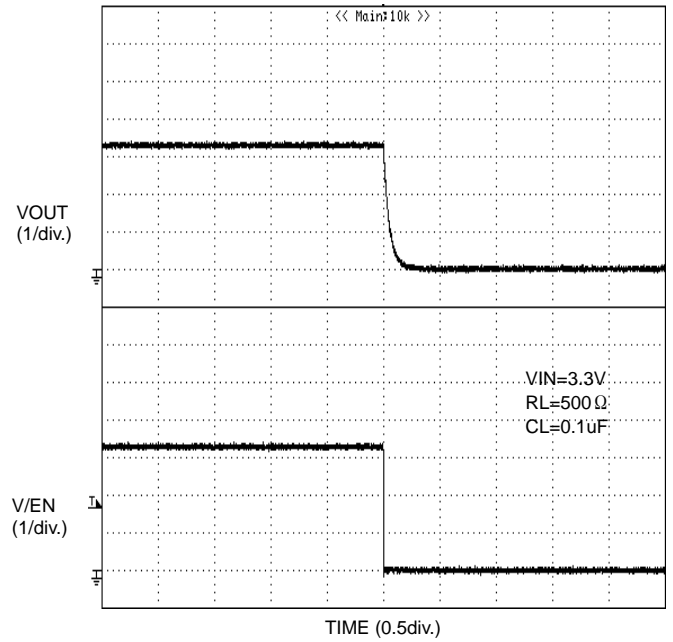


Figure 29. Output turn off response

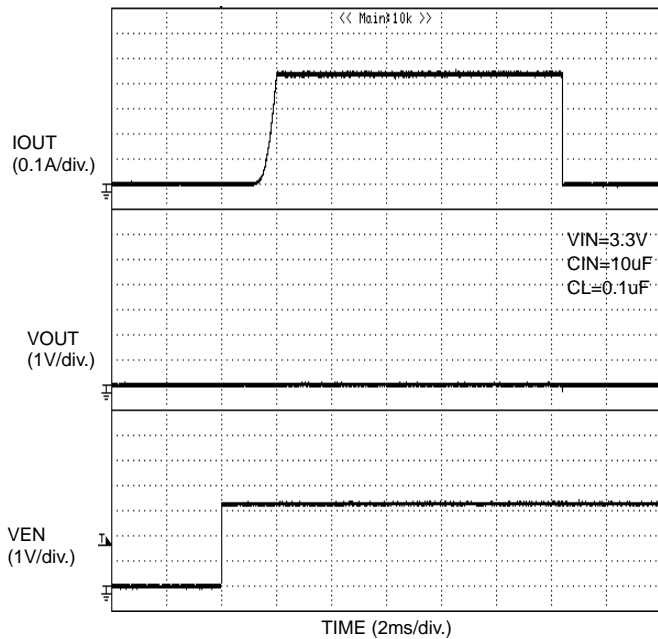


Figure 30. Current limit response
Enable into short circuit
(BD2202G)

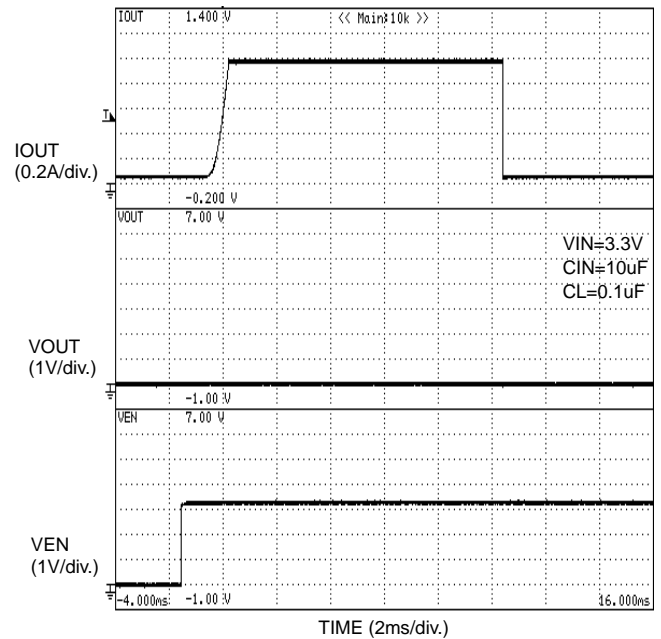


Figure 31. Current limit response
Enable into short circuit
(BD2206G)

Typical Wave Forms - continued

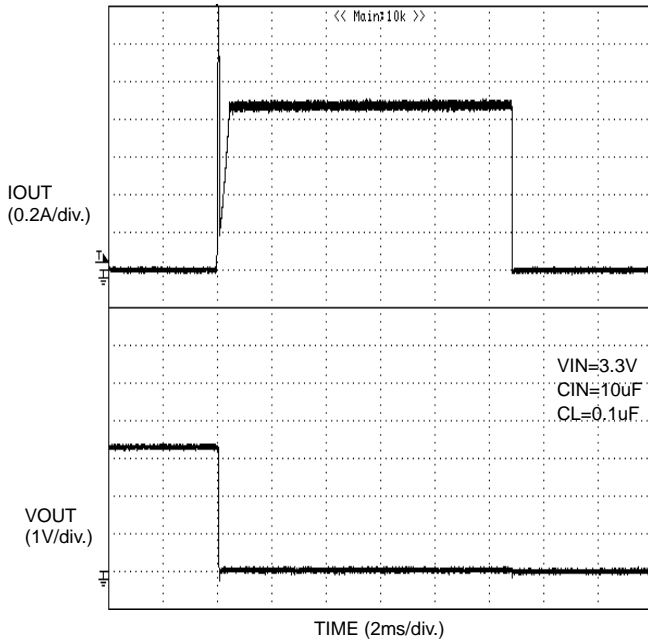


Figure 32. Current limit response
Output shorted to GND
(BD2202G)

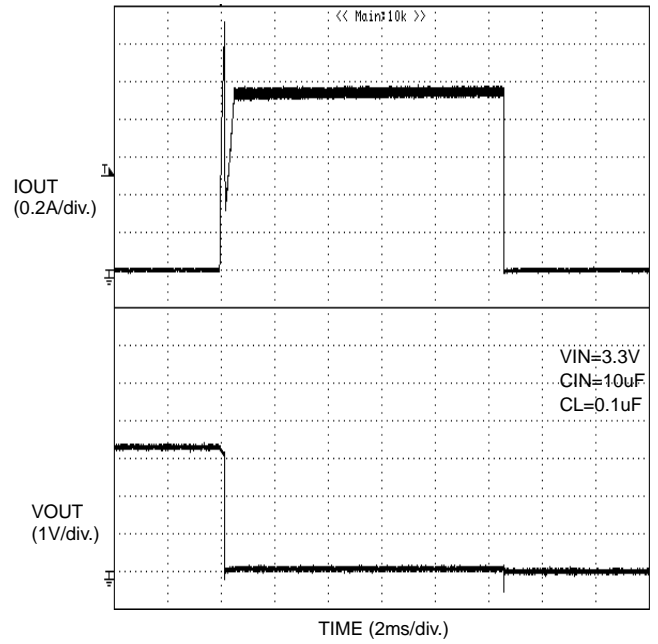


Figure 33. Current limit response
Output shorted to GND
(BD2206G)

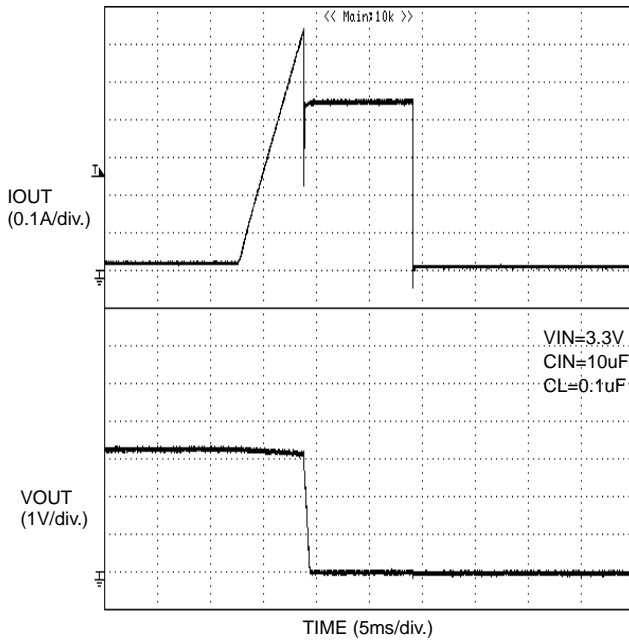


Figure 34. Current limit response
Ramped load (1A/10ms)
(BD2202G)

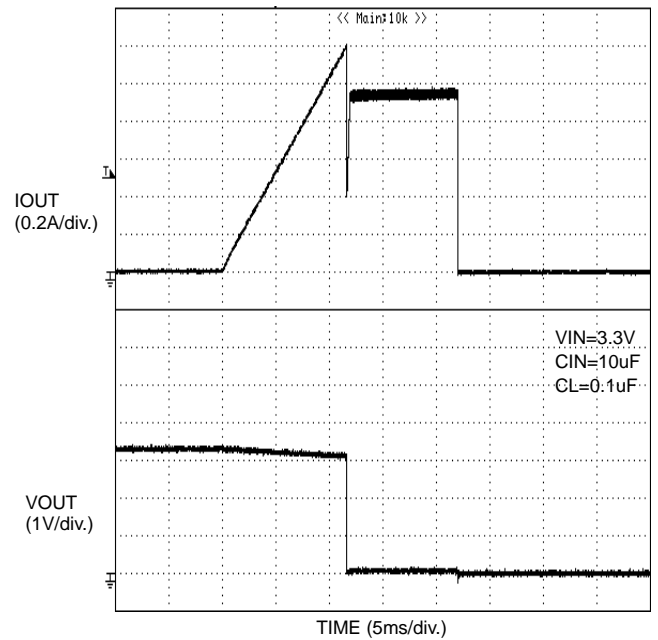


Figure 35. Current limit response
Ramped load (1A/10ms)
(BD2206G)

Typical Wave Forms - continued

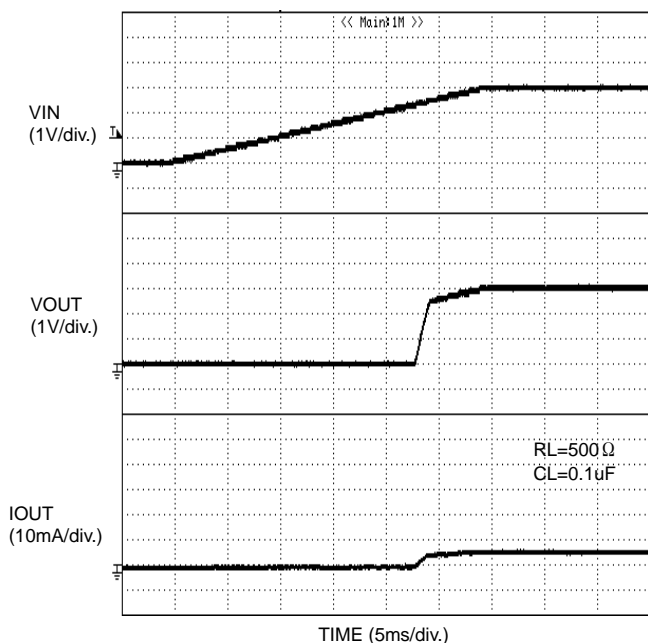


Figure 36. UVLO V_{IN} rising

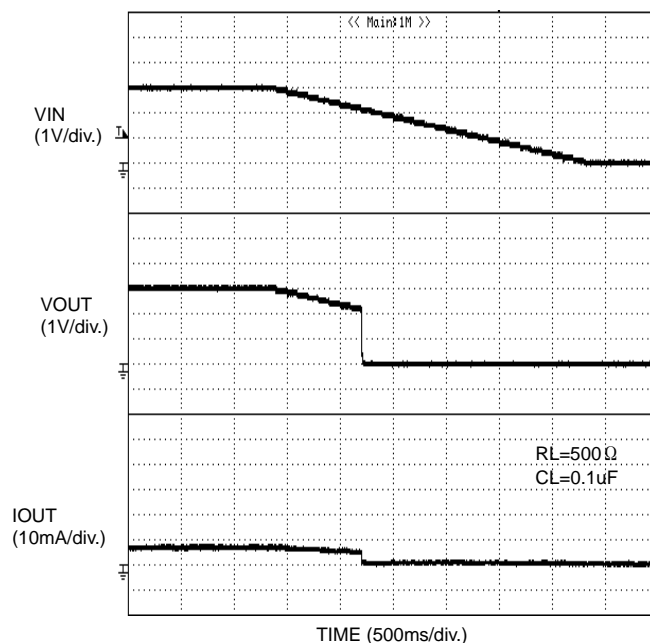
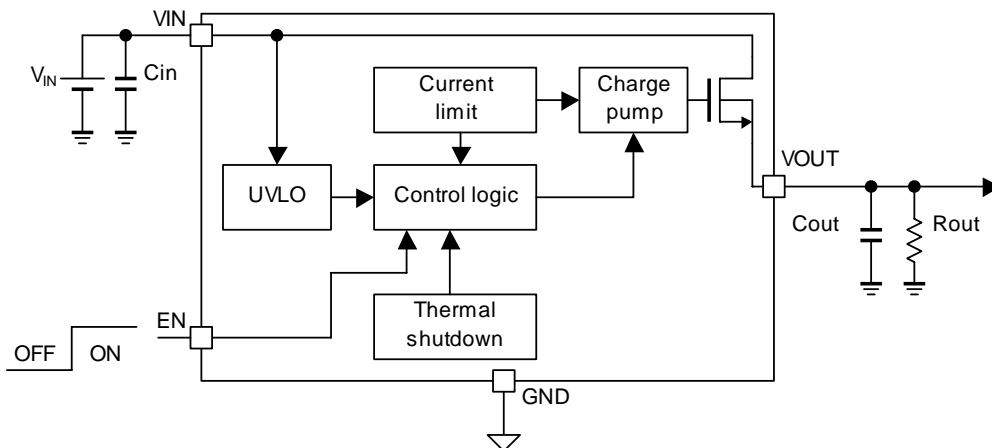


Figure 37. UVLO V_{IN} falling

Typical application circuit



Application Information

When excessive current flows due to output short-circuit or so, ringing occurs because of inductance between power source line to IC, and may cause bad influences on IC operations. In order to avoid this case, connect a bypass capacitor across IN terminal and GND terminal of IC. 1 μ F or higher is recommended.

This application circuit does not guarantee its operation.

When using the circuit with changes to the external circuit constants, make sure to leave an adequate margin for external components including AC/DC characteristics as well as dispersion of the IC.

Operation Description

BD2202G and BD2206G are high side switch ICs with over-current protection function. The operating voltage range is from 2.7V to 3.6V and the current limit value is set to 400mA and 1A respectively.

When an over-current condition lasts longer than its over-current shutdown time, the switch turns OFF. The OFF switch is set to latch mode. The switch set to latch mode returns to normal by toggling EN pin from High to Low to High.

1. Switch On/Off control

VIN terminal and VOUT terminal are connected to the drain and the source of switch MOSFET respectively. And the VIN terminal is used also as power source input to internal control circuit.

When the switch is turned on from EN control input, VIN and VOUT are connected by a 150mΩ switch. In normal condition, the switch is bidirectional. Therefore, when the voltage of VOUT is higher than VIN the current flows from VOUT to VIN.

In the switch MOSFET, there is a parasitic diode (body diode) between drain and source. So, even when the switch is off, when voltage of VOUT is higher than VIN, the current flows through the body diode from VOUT to VIN.

2. Over current detection (OCD)

The over current detection circuit limits current flowing in switch MOSFET when it exceeds its limit threshold. There are three types of responses against over current. The over current detection circuit is in operation when the power switch is ON (when EN signal is active).

2-1 When the switch is turned on while the output is in short-circuit status

When the switch is turned on while the output is in short-circuit status, the switch goes into current limit status immediately.

2-2 When the output short-circuits while the switch is on

When the output short-circuits or high-current load is connected while the switch is on, very large current flows until the over current limit circuit reacts. When the current detection and limit circuit works, current limitation is carried out.

2-3 When the output current increases gradually

When the output current increases gradually, current limitation does not work until the output current exceeds the over current detection value. When it exceeds the detection value, current limitation is carried out.

3. Over current shutdown

When the over current detection circuit detects an over current, TBLANK timer starts working. When the over current condition disappears before TBLANK2 stage, TBLANK timer is reset. When the over current condition progresses to more than TBLANK1, the switch is shut off. The OFF switch is set to latch off mode. The latch is reset when EN terminal is toggled or when UVLO is detected.

4. Under voltage lockout (UVLO)

UVLO keeps the power switch off until VIN voltage exceeds 2.3V (Typ.). Moreover, from a power switch ON situation, if VIN voltage drops to 2.2V (Typ.), the power switch is set to OFF. UVLO has a 100mV hysteresis. The under voltage lock out circuit is in operation when power switch is ON (when EN signal is active).

5. Thermal shutdown

When the chip temperature increases to 160°C (Typ.), the thermal shut down circuit works and the power switch is turned OFF. When the chip temperature falls to 140°C (Typ.), the power switch output returns to normal. This operation will repeat itself until the causes of the chip temperature rise are removed or until the power switch output is turned off.

The thermal shutdown circuit is in operation when the power switch is ON (when EN signal is active).

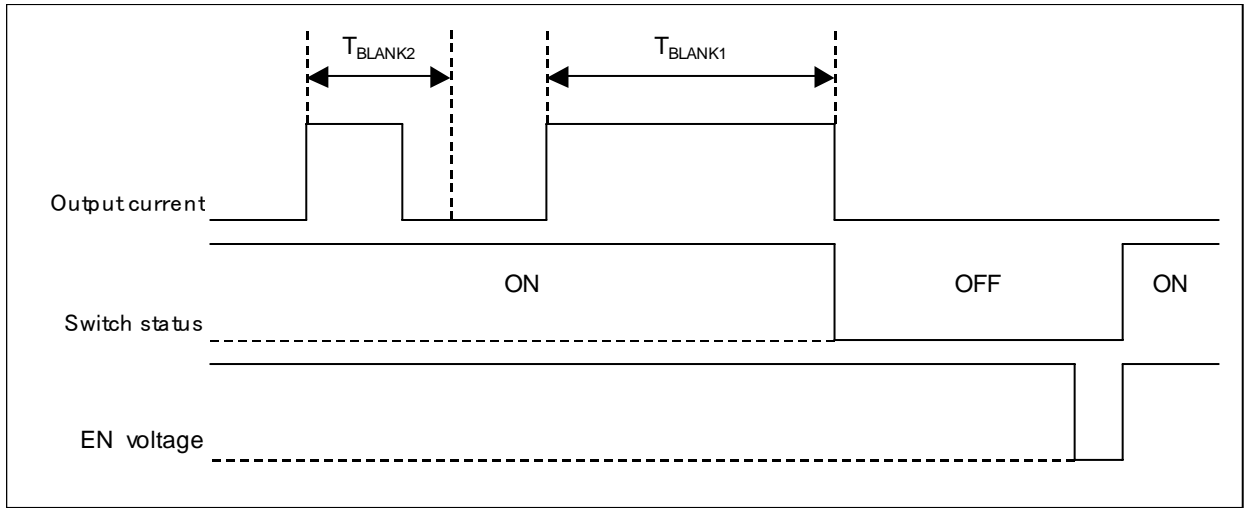


Figure 38. Over-current detection, shutdown operation (return with EN input)

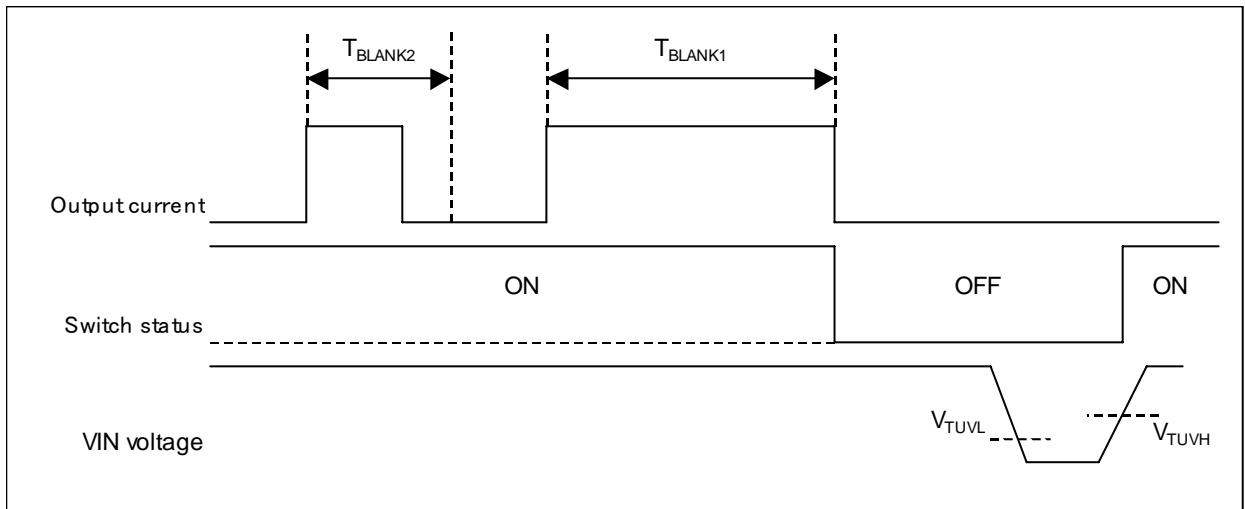


Figure 39. Over-current detection, shutdown operation (return with UVLO operation)

Power Dissipation
(SSOP5)

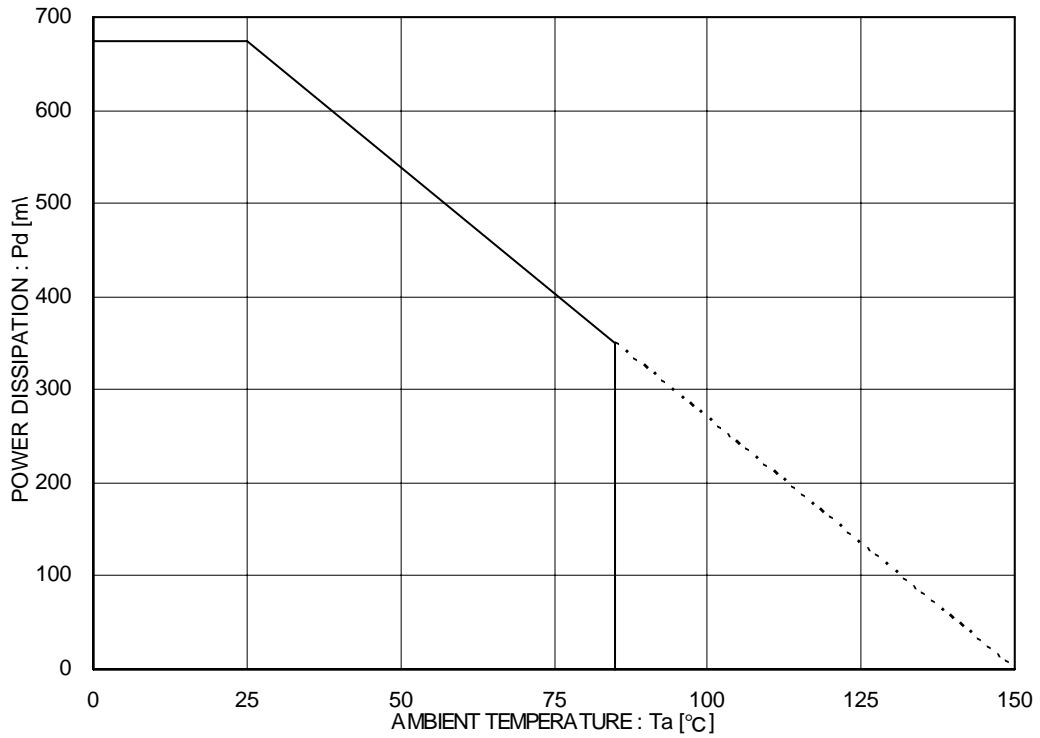


Figure 40. Power dissipation curve (Pd-Ta Curve)

I/O Equivalence Circuit

Pin Name	Pin Number	Equivalence circuits
EN	3	
VOUT	5	

Operational Notes

(1) Absolute Maximum Ratings

Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

(2) Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

(3) Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

(4) Power Supply Lines

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

(5) Ground voltage

The voltage of the ground pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.

(6) Short between Pins and Mounting Errors

Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.

(7) Operation under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

(8) Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

(9) Regarding Input Pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When $GND > Pin A$ and $GND > Pin B$, the P-N junction operates as a parasitic diode.

When $GND > Pin B$, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

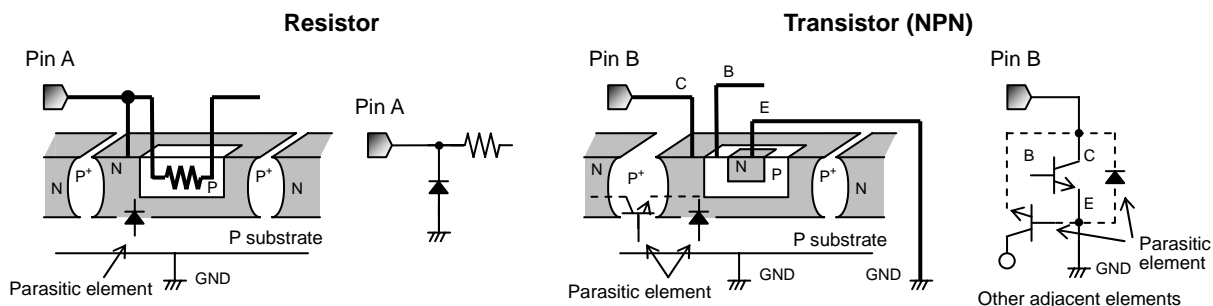


Figure 41. Example of monolithic IC structure

(10)GND Wiring Pattern

When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on the GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.

(11)External capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

(12)Thermal Shutdown Circuit (TSD)

The IC incorporates a built-in thermal shutdown circuit, which is designed to turn off the IC when the internal temperature of the IC reaches a specified value. Do not continue to operate the IC after this function is activated. Do not use the IC in conditions where this function will always be activated.

(13)Thermal Consideration

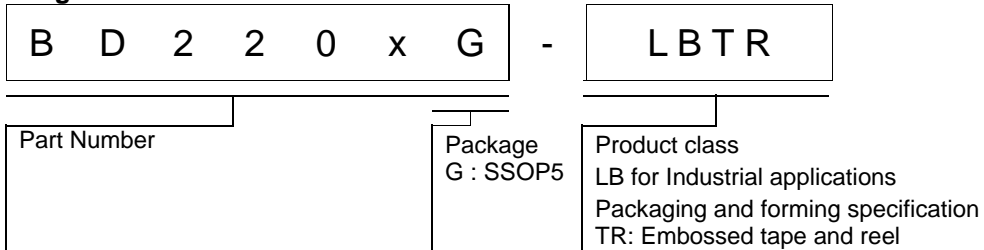
Use a thermal design that allows for a sufficient margin by taking into account the permissible power dissipation (P_d) in actual operating conditions. Consider P_c that does not exceed P_d in actual operating conditions ($P_c \geq P_d$).

Package Power dissipation : $P_d (W) = (T_{jmax} - T_a) / \theta_{ja}$

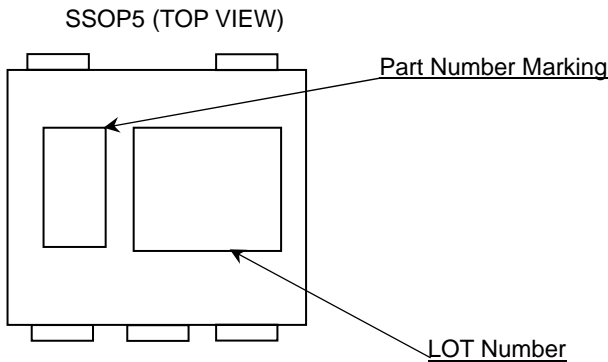
Power dissipation : $P_c (W) = (V_{cc} - V_o) \times I_o + V_{cc} \times I_b$

(T_{jmax} : Maximum junction temperature=150°C, T_a : Peripheral temperature[°C],
 θ_{ja} : Thermal resistance of package-ambience[°C/W], P_d : Package Power dissipation [W],
 P_c : Power dissipation [W], V_{cc} : Input Voltage, V_o : Output Voltage, I_o : Load, I_b : Bias Current)

Ordering Information

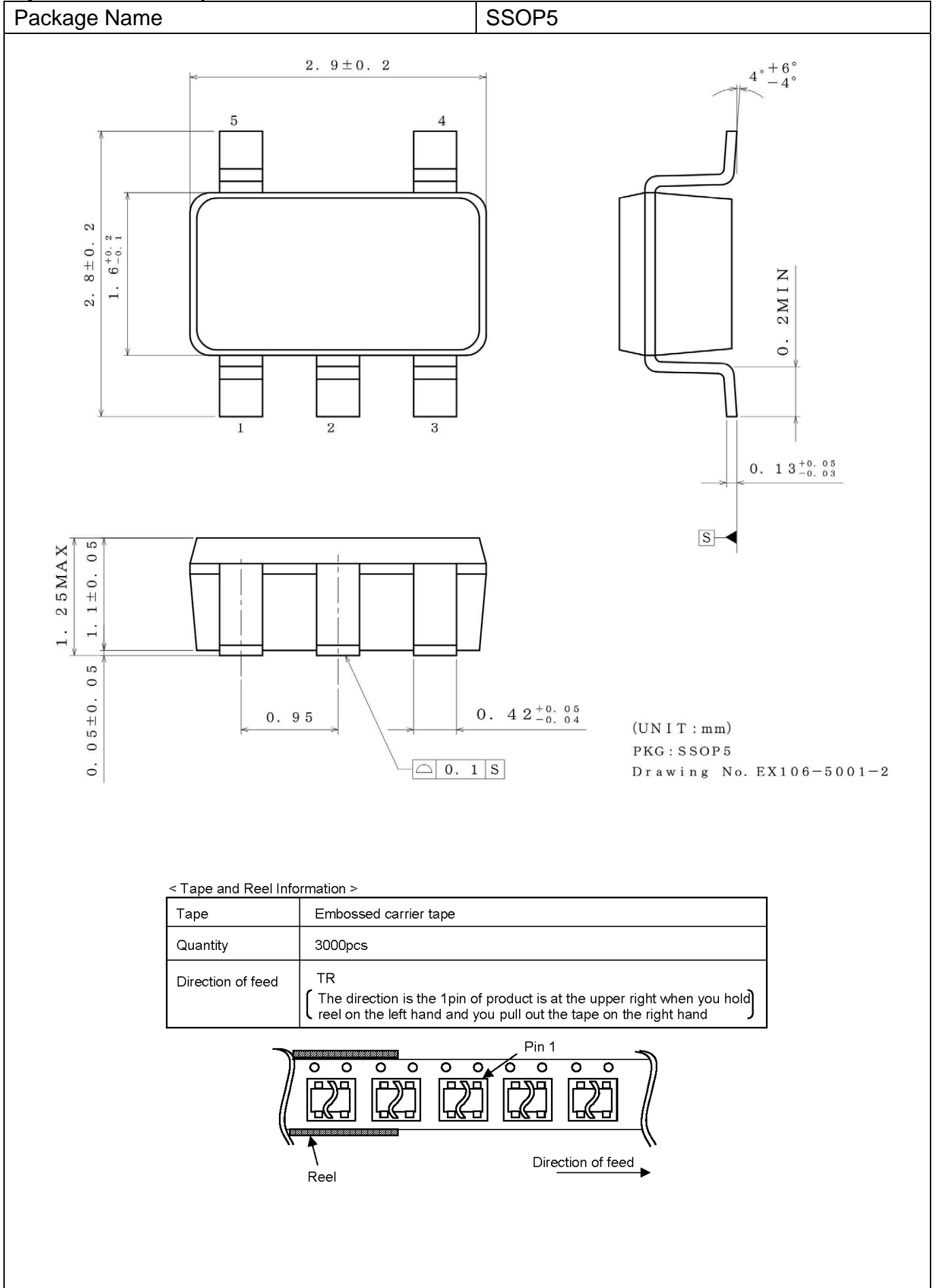


Marking Diagram



Part Number	Part Number Marking
BD2202G	AN
BD2206G	AR

Physical Dimension Tape and Reel Information



Revision History

Date	Revision	Changes
13.Mar.2012	001	New Release
21.Feb.2014	002	Delete sentence "and log life cycle" in General Description and Futures (page 1). Change "Industrial Applications" to "Industrial Equipment" in Applications (page 1). Applied new style ("title", "Ordering Information" and "Physical Dimension Tape and Reel Information").

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(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

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 - [f] Sealing or coating our Products with resin or other coating materials
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6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
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8. Confirm that operation temperature is within the specified range described in the product specification.
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For details, please refer to ROHM Mounting specification

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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
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